

XS156B3

Monocrystalline X-Cells

Dimension	156.75mm x 156.75mm ± 0.25mm			
Diagonal	210mm ± 0.25mm (round chamfers)			
Thickness(Si)	180 ± 20 μm			
Front	Anisotropically texturized surface and dark silicon nitride anti-reflection coatings			
	1.4mm silver busbars			
Back	Full-surface aluminum back-surface field			
	2.0mm (silver / aluminum) discontinuous soldering pads			



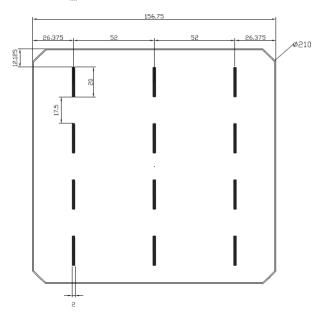
Features

- > High conversion efficiencies resulting in superior power output performance
- Outstanding power output even in low light or high temperature conditions
- Optimized design for ease of soldering and lamination
- > Long-term stability, reliability and performance
- > Low breakage rate
- > Color uniformity

26.375 52 26.375 52 26.375 52 26.375 52 26.375 52 26.375

○ Production and Quality Control

- > Precision cell efficiency sorting procedures
- > Stringent criteria for color uniformity and appearance
- Reverse current and shunt resistance screening
- > ISO9001, ISO14001 and OHSAS 18001 certificated
- Calibrated against Fraunhofer ISE



^{*} See the reverse side for more detail



Electrical Performance

		202	201	200	199	198
Efficiency	Eff(%)	20.20	20.10	20.00	19.90	19.80
Power	Ppm(W)	4.94	4.91	4.89	4.86	4.84
Max. Power Current	Ipm(A)	8.89	8.86	8.82	8.79	8.76
Short Circuit Current	t Isc(A)	9.37	9.34	9.31	9.27	9.24
Max. Power Voltage	Vpm(V)	0.555	0.555	0.554	0.553	0.552
Open Circuit Voltage	Voc(V)	0.649	0.648	0.647	0.647	0.646
Efficiency Code		197	196	195	194	
Efficiency	Eff(%)	19.70	19.60	19.50	19.40	
Power	Ppm(W)	4.81	4.79	4.76	4.74	
Max. Power Current	Ipm(A)	8.72	8.69	8.66	8.62	
Short Circuit Current	l Isc(A)	9.21	9.17	9.14	9.11	
Max. Power Voltage	Vpm(V)	0.552	0.551	0.550	0.540	

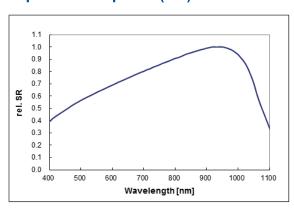
Standard test conditions: AM1.5, 1000W/m², 25°C. Average accuracy of all tested figures is ±1.5% rel.

○ Temperature Coefficients

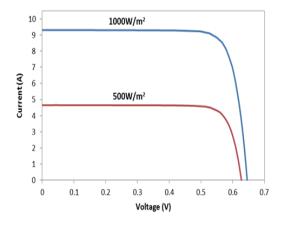
Current Temperature Coefficient	α(Isc)	0. 04 %/°C
Voltage Temperature Coefficient	eta(Voc)	-0.3 2 %/°C
Power Temperature Coefficient	γ (Pmax)	-0.42%/°C

Standard test conditions : AM1.5, 1000W/m², 25°C.

Spectral Response(SR)



▶ IV Curve



Specifications subject to change without prior notice. MOTECH reserves the rights of final interpretation and revision of this datasheet.

Oct 2018 Pi2.3A_V04

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